74LVQ08 Low Voltage Quad 2-Input AND Gate

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General Description

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SEMICONDUCTOR

The LVQ08 contains four, 2-input AND gates.

Features

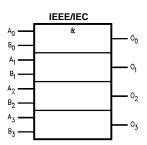
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and
- dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- \blacksquare Guaranteed incident wave switching into 75 $\!\Omega$

Ordering Code:

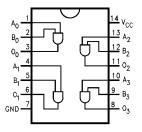
Order Number	Package Number	Package Description				
74LVQ08SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow				
74LVQ08SJ M14D 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide						
Devices also successfully in Tana and David Openia in the sufficiency (VII) to the and size and						

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin	Names	Description		
A	_n , B _n	Inputs		
	O _n	Outputs		

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Absolute Maximum Ratings(Note 1)

Supply Voltage (V _{CC})	-0.5V to +7.0V
DC Input Diode Current (I _{IK})	
$V_1 = -0.5V$	–20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (VI)	–0.5V to V _{CC} + 0.5V
DC Output Diode Current (I _{OK})	
$V_{O} = -0.5V$	–20 mA
$V_{O} = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V _O)	–0.5V to V_{CC} + 0.5V
DC Output Source	
or Sink Current (I _O)	±50 mA
DC V _{CC} or Ground Current	
(I _{CC} or I _{GND})	±200 mA
Storage Temperature (T _{STG})	$-65^{\circ}C$ to $+150^{\circ}C$
DC Latch-Up Source or	

Recommended Operating Conditions (Note 2)

2.0V to 3.6V
0V to V_{CC}
0V to V _{CC}
$-40^\circ C$ to $+85^\circ C$
125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

±100 mA

DC Electrical Characteristics							
Symbol	Parameter	V _{cc}	$T_A = +25^{\circ}C$		$\textbf{T}_{\textbf{A}}=-40^{\circ}\textbf{C} \text{ to } +85^{\circ}\textbf{C}$	Units	Conditions
Symbol		(V) 3.0	Тур	Guaranteed Limits			Conditions
V _{IH}	Minimum High Level Input Voltage		1.5	2.0	2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
V _{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$
V _{OH}	Minimum High Level	3.0	2.99	2.9	2.9	V	I _{OUT} = -50 μA
	Output Voltage			2.58	2.48	V	$V_{IN} = V_{IL} \text{ or } V_{IH} \text{ (Note 3)}$ $I_{OH} = -12 \text{ mA}$
V _{OL}	Maximum Low Level	3.0	0.002	0.1	0.1	V	I _{OUT} = 50 μA
	Output Voltage	3.0		0.36	0.44	V	$V_{IN} = V_{IL} \text{ or } V_{IH} \text{ (Note 3)}$ $I_{OL} = 12 \text{ mA}$
I _{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μΑ	$V_I = V_{CC}$, GND
I _{OLD}	Minimum Dynamic	3.6			36	mA	V _{OLD} = 0.8V Max (Note 5)
I _{OHD}	Output Current (Note 4)	3.6			-25	mA	V _{OHD} = 2.0V Min (Note 5)
I _{CC}	Maximum Quiescent Supply Current	3.6		2.0	20.0	μΑ	V _{IN} = V _{CC} or GND
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	3.3	0.4	0.8		V	(Note 6)(Note 7)
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	3.3	-0.4	-0.8		V	(Note 6)(Note 7)
V _{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.8	2.0		V (Note 6)(Note 8)	
V _{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.8	0.8		V	(Note 6)(Note 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ. Note 6: Worst case package.

Sink Current

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n - 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold $(V_{IHD}), f = 1 MHz.$

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AC Electrical Characteristics

				T _A = +25°C			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		
Symbol	Parameter	v _{cc}	$C_L = 50 \text{ pF}$			$C_L = 50 \text{ pF}$		Units	
		(V)	Min	Тур	Max	Min	Max		
t _{PLH}	Propagation Delay	2.7	1.5	9.0	13.4	1.0	14.0		
		3.3 ± 0.3	1.5	7.5	9.5	1.0	10.0	ns	
t _{PHL}	Propagation Delay	2.7	1.5	8.4	12.0	1.0	13.0		
		$\textbf{3.3}\pm\textbf{0.3}$	1.5	7.0	8.5	1.0	9.0	ns	
t _{OSHL}	Output to Output Skew	2.7		1.0	1.5		1.5		
t _{OSLH}	(Note 9)	3.3 ± 0.3		1.0	1.5		1.5	ns	

 t_{OSLH} (Note 9)
 3.3 ± 0.3 1.0 1.5 1.5

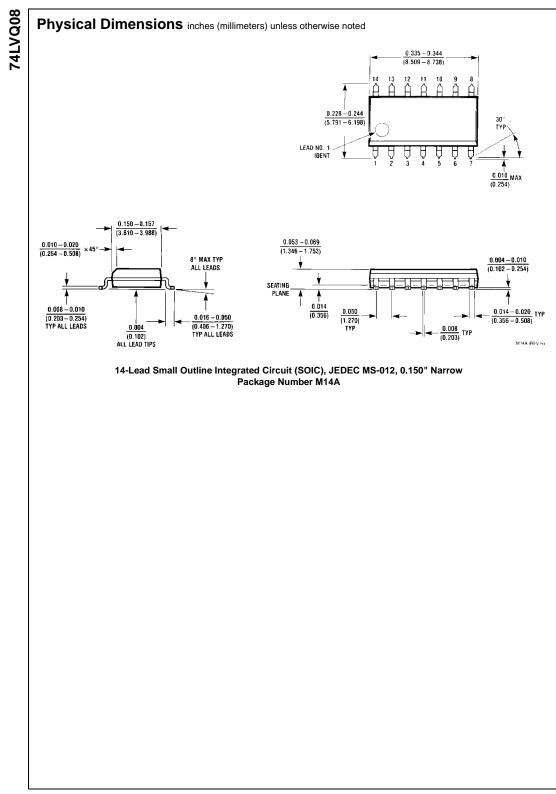
 Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

Symbol	Parameter	Тур	Units	Conditions
CIN	Input Capacitance	4.5	pF	V _{CC} = Open
C _{PD} (Note 10)	Power Dissipation Capacitance	17	pF	V _{CC} = 3.3V

Note 10: C_{PD} is measured at 10 MHz.

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